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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	80MHz
Connectivity	CANbus, EBI/EMI, I ² C, IrDA, LINbus, MMC/SD, QSPI, SAI, SPI, SWPMI, UART/USART, USB OTG
Peripherals	Brown-out Detect/Reset, DMA, LCD, PWM, WDT
Number of I/O	82
Program Memory Size	1MB (1M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	128K x 8
Voltage - Supply (Vcc/Vdd)	1.71V ~ 3.6V
Data Converters	A/D 16x12b; D/A 2x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/stmicroelectronics/stm32l476vgt6u

3 Functional overview

3.1 ARM® Cortex®-M4 core with FPU

The ARM® Cortex®-M4 with FPU processor is the latest generation of ARM processors for embedded systems. It was developed to provide a low-cost platform that meets the needs of MCU implementation, with a reduced pin count and low-power consumption, while delivering outstanding computational performance and an advanced response to interrupts.

The ARM® Cortex®-M4 with FPU 32-bit RISC processor features exceptional code-efficiency, delivering the high-performance expected from an ARM core in the memory size usually associated with 8- and 16-bit devices.

The processor supports a set of DSP instructions which allow efficient signal processing and complex algorithm execution.

Its single precision FPU speeds up software development by using metalanguage development tools, while avoiding saturation.

With its embedded ARM core, the STM32L476xx family is compatible with all ARM tools and software.

Figure 1 shows the general block diagram of the STM32L476xx family devices.

3.2 Adaptive real-time memory accelerator (ART Accelerator™)

The ART Accelerator™ is a memory accelerator which is optimized for STM32 industry-standard ARM® Cortex®-M4 processors. It balances the inherent performance advantage of the ARM® Cortex®-M4 over Flash memory technologies, which normally requires the processor to wait for the Flash memory at higher frequencies.

To release the processor near 100 DMIPS performance at 80MHz, the accelerator implements an instruction prefetch queue and branch cache, which increases program execution speed from the 64-bit Flash memory. Based on CoreMark benchmark, the performance achieved thanks to the ART accelerator is equivalent to 0 wait state program execution from Flash memory at a CPU frequency up to 80 MHz.

3.3 Memory protection unit

The memory protection unit (MPU) is used to manage the CPU accesses to memory to prevent one task to accidentally corrupt the memory or resources used by any other active task. This memory area is organized into up to 8 protected areas that can in turn be divided up into 8 subareas. The protection area sizes are between 32 bytes and the whole 4 gigabytes of addressable memory.

The MPU is especially helpful for applications where some critical or certified code has to be protected against the misbehavior of other tasks. It is usually managed by an RTOS (real-time operating system). If a program accesses a memory location that is prohibited by the MPU, the RTOS can detect it and take action. In an RTOS environment, the kernel can dynamically update the MPU area setting, based on the process to be executed.

The MPU is optional and can be bypassed for applications that do not need it.

Many features are shared with those of the general-purpose TIMx timers (described in [Section 3.24.2](#)) using the same architecture, so the advanced-control timers can work together with the TIMx timers via the Timer Link feature for synchronization or event chaining.

3.24.2 General-purpose timers (TIM2, TIM3, TIM4, TIM5, TIM15, TIM16, TIM17)

There are up to seven synchronizable general-purpose timers embedded in the STM32L476 (see [Table 10](#) for differences). Each general-purpose timer can be used to generate PWM outputs, or act as a simple time base.

- TIM2, TIM3, TIM4 and TIM5

They are full-featured general-purpose timers:

- TIM2 and TIM5 have a 32-bit auto-reload up/downcounter and 32-bit prescaler
- TIM3 and TIM4 have 16-bit auto-reload up/downcounter and 16-bit prescaler.

These timers feature 4 independent channels for input capture/output compare, PWM or one-pulse mode output. They can work together, or with the other general-purpose timers via the Timer Link feature for synchronization or event chaining.

The counters can be frozen in debug mode.

All have independent DMA request generation and support quadrature encoders.

- TIM15, 16 and 17

They are general-purpose timers with mid-range features:

They have 16-bit auto-reload upcounters and 16-bit prescalers.

- TIM15 has 2 channels and 1 complementary channel
- TIM16 and TIM17 have 1 channel and 1 complementary channel

All channels can be used for input capture/output compare, PWM or one-pulse mode output.

The timers can work together via the Timer Link feature for synchronization or event chaining. The timers have independent DMA request generation.

The counters can be frozen in debug mode.

3.24.3 Basic timers (TIM6 and TIM7)

The basic timers are mainly used for DAC trigger generation. They can also be used as generic 16-bit timebases.

3.24.4 Low-power timer (LPTIM1 and LPTIM2)

The devices embed two low-power timers. These timers have an independent clock and are running in Stop mode if they are clocked by LSE, LSI or an external clock. They are able to wakeup the system from Stop mode.

LPTIM1 is active in Stop 0, Stop 1 and Stop 2 modes.

LPTIM2 is active in Stop 0 and Stop 1 mode.

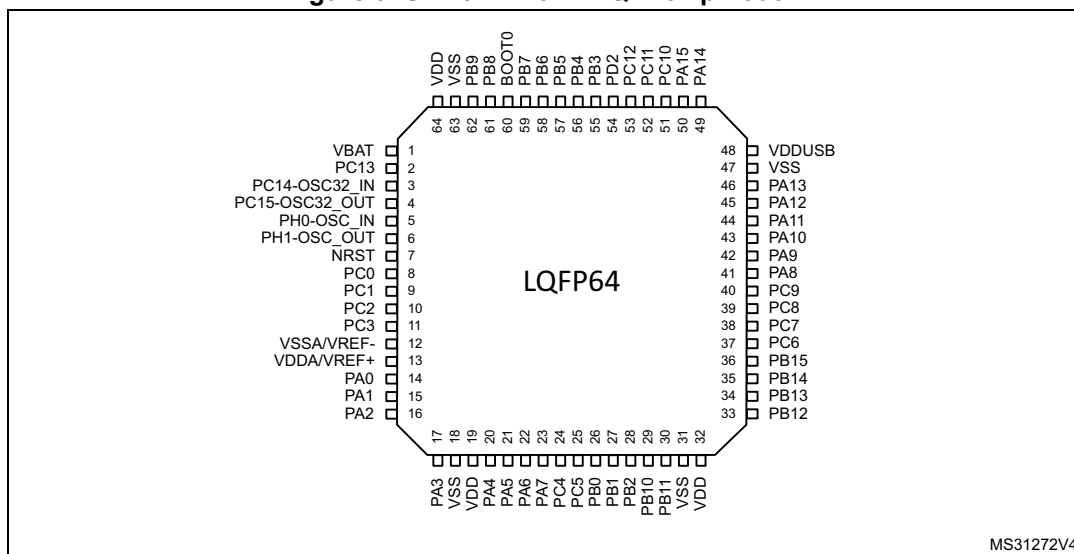
3.36 Quad SPI memory interface (QUADSPI)

The Quad SPI is a specialized communication interface targeting single, dual or quad SPI flash memories. It can operate in any of the three following modes:

- Indirect mode: all the operations are performed using the QUADSPI registers
- Status polling mode: the external flash status register is periodically read and an interrupt can be generated in case of flag setting
- Memory-mapped mode: the external flash is memory mapped and is seen by the system as if it were an internal memory

The Quad SPI interface supports:

- Three functional modes: indirect, status-polling, and memory-mapped
- SDR and DDR support
- Fully programmable opcode for both indirect and memory mapped mode
- Fully programmable frame format for both indirect and memory mapped mode
- Each of the 5 following phases can be configured independently (enable, length, single/dual/quad communication)
 - Instruction phase
 - Address phase
 - Alternate bytes phase
 - Dummy cycles phase
 - Data phase
- Integrated FIFO for reception and transmission
- 8, 16, and 32-bit data accesses are allowed
- DMA channel for indirect mode operations
- Programmable masking for external flash flag management
- Timeout management
- Interrupt generation on FIFO threshold, timeout, status match, operation complete, and access error

Figure 9. STM32L476Rx LQFP64 pinout⁽¹⁾

1. The above figure shows the package top view.

Table 14. Legend/abbreviations used in the pinout table

Name	Abbreviation	Definition
Pin name	Unless otherwise specified in brackets below the pin name, the pin function during and after reset is the same as the actual pin name	
Pin type	S	Supply pin
	I	Input only pin
	I/O	Input / output pin
I/O structure	FT	5 V tolerant I/O
	TT	3.6 V tolerant I/O
	B	Dedicated BOOT0 pin
	RST	Bidirectional reset pin with embedded weak pull-up resistor
	Option for TT or FT I/Os	
	_f ⁽¹⁾	I/O, Fm+ capable
	_l ⁽²⁾	I/O, with LCD function supplied by V _{LCD}
	_u ⁽³⁾	I/O, with USB function supplied by V _{DDUSB}
	_a ⁽⁴⁾	I/O, with Analog switch function supplied by V _{DDA}
	_s ⁽⁵⁾	I/O supplied only by V _{DDIO2}
Notes	Unless otherwise specified by a note, all I/Os are set as analog inputs during and after reset.	
Pin functions	Alternate functions	Functions selected through GPIOx_AFR registers
	Additional functions	Functions directly selected/enabled through peripheral registers

1. The related I/O structures in [Table 15](#) are: FT_f, FT_fa, FT_fl, FT_fla.

Table 15. STM32L476xxSTM32L476xx pin definitions (continued)

Pin Number						Pin name (function after reset)	Pin type	I/O structure	Notes	Pin functions	
LQFP64	WLCSP72	WLCSP81	LQFP100	UFPGA132	LQFP144					Alternate functions	Additional functions
-	-	-	82	B9	115	PD1	I/O	FT	-	SPI2_SCK, DFSDM_CKIN7, CAN1_TX, FMC_D3, EVENTOUT	-
54	A3	A3	83	C8	116	PD2	I/O	FT_I	-	TIM3_ETR, USART3_RTS_DE, UART5_RX, TSC_SYNC, LCD_COM7/LCD_SEG31/ LCD_SEG43, SDMMC1_CMD, EVENTOUT	-
-	-	-	84	B8	117	PD3	I/O	FT	-	SPI2_MISO, DFSDM_DATIN0, USART2_CTS, FMC_CLK, EVENTOUT	-
-	-	E5	85	B7	118	PD4	I/O	FT	-	SPI2_MOSI, DFSDM_CKIN0, USART2_RTS_DE, FMC_NOE, EVENTOUT	-
-	-	D4	86	A6	119	PD5	I/O	FT	-	USART2_TX, FMC_NWE, EVENTOUT	-
-	-	-	-	-	120	VSS	S	-	-	-	-
-	-	E4	-	-	121	VDD	S	-	-	-	-
-	-	D5	87	B6	122	PD6	I/O	FT	-	DFSDM_DATIN1, USART2_RX, FMC_NWAIT, SAI1_SD_A, EVENTOUT	-
-	-	D6	88	A5	123	PD7	I/O	FT	-	DFSDM_CKIN1, USART2_CK, FMC_NE1, EVENTOUT	-
-	A4	A4	-	D9	124	PG9	I/O	FT_s	-	SPI3_SCK, USART1_TX, FMC_NCE3/FMC_NE2, SAI2_SCK_A, TIM15_CH1N, EVENTOUT	-
-	B4	B4	-	D8	125	PG10	I/O	FT_s	-	LPTIM1_IN1, SPI3_MISO, USART1_RX, FMC_NE3, SAI2_FS_A, TIM15_CH1, EVENTOUT	-
-	C4	C4	-	G3	126	PG11	I/O	FT_s	-	LPTIM1_IN2, SPI3_MOSI, USART1_CTS, SAI2_MCLK_A, TIM15_CH2, EVENTOUT	-

Table 15. STM32L476xxSTM32L476xx pin definitions (continued)

Pin Number						Pin name (function after reset)	Pin type	I/O structure	Notes	Pin functions	
LQFP64	WLCSP72	WLCSP81	LQFP100	UFBGA132	LQFP144					Alternate functions	Additional functions
59	A7	A7	93	B4	137	PB7	I/O	FT_flg	-	LPTIM1_IN2, TIM4_CH2, TIM8_BKIN, I2C1_SDA, DFSDM_CKIN5, USART1_RX, UART4_CTS, TSC_G2_IO4, LCD_SEG21, FMC_NL, TIM8_BKIN_COMP1, TIM17_CH1N, EVENTOUT	COMP2_INM, PVD_IN
60	D7	D7	94	A4	138	BOOT0	I	-	-	-	-
61	E7	E7	95	A3	139	PB8	I/O	FT_fl	-	TIM4_CH3, I2C1_SCL, DFSDM_DATIN6, CAN1_RX, LCD_SEG16, SDMMC1_D4, SAI1_MCLK_A, TIM16_CH1, EVENTOUT	-
62	E8	E8	96	B3	140	PB9	I/O	FT_fl	-	IR_OUT, TIM4_CH4, I2C1_SDA, SPI2_NSS, DFSDM_CKIN6, CAN1_TX, LCD_COM3, SDMMC1_D5, SAI1_FS_A, TIM17_CH1, EVENTOUT	-
-	-	-	97	C3	141	PE0	I/O	FT_I	-	TIM4_ETR, LCD_SEG36, FMC_NBL0, TIM16_CH1, EVENTOUT	-
-	-	-	98	A2	142	PE1	I/O	FT_I	-	LCD_SEG37, FMC_NBL1, TIM17_CH1, EVENTOUT	-
63	A8	A8	99	D3	143	VSS	S	-	-	-	-
64	A9	A9	100	C4	144	VDD	S	-	-	-	-

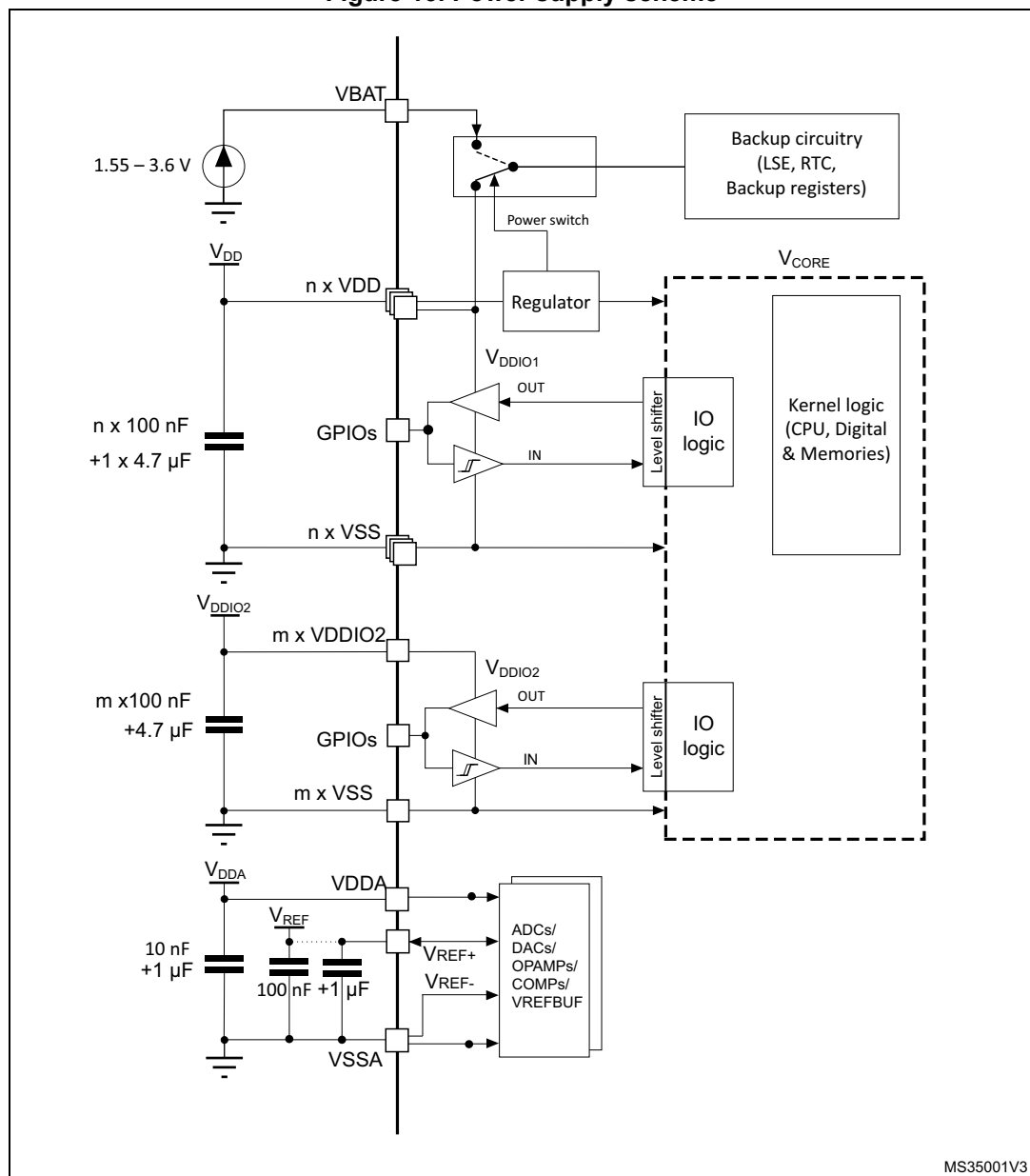
1. PC13, PC14 and PC15 are supplied through the power switch. Since the switch only sinks a limited amount of current (3 mA), the use of GPIOs PC13 to PC15 in output mode is limited:
 - The speed should not exceed 2 MHz with a maximum load of 30 pF
 - These GPIOs must not be used as current sources (e.g. to drive an LED).
2. After a Backup domain power-up, PC13, PC14 and PC15 operate as GPIOs. Their function then depends on the content of the RTC registers which are not reset by the system reset. For details on how to manage these GPIOs, refer to the Backup domain and RTC register descriptions in the RM0351 reference manual.
3. After reset, these pins are configured as JTAG/SW debug alternate functions, and the internal pull-up on PA15, PA13, PB4 pins and the internal pull-down on PA14 pin are activated.

Table 16. Alternate function AF0 to AF7 (for AF8 to AF15 see [Table 17](#)) (continued)

Port		AF0	AF1	AF2	AF3	AF4	AF5	AF6	AF7
		SYS_AF	TIM1/TIM2/ TIM5/TIM8/ LPTIM1	TIM1/TIM2/ TIM3/TIM4/ TIM5	TIM8	I2C1/I2C2/I2C3	SPI1/SPI2	SPI3/DFSDM	USART1/ USART2/ USART3
Port D	PD0	-	-	-	-	-	SPI2_NSS	DFSDM_DATIN7	-
	PD1	-	-	-	-	-	SPI2_SCK	DFSDM_CKIN7	-
	PD2	-	-	TIM3_ETR	-	-	-	-	USART3_RTS_ DE
	PD3	-	-	-	-	-	SPI2_MISO	DFSDM_DATIN0	USART2_CTS
	PD4	-	-	-	-	-	SPI2_MOSI	DFSDM_CKIN0	USART2_RTS_ DE
	PD5	-	-	-	-	-	-	-	USART2_TX
	PD6	-	-	-	-	-	-	DFSDM_DATIN1	USART2_RX
	PD7	-	-	-	-	-	-	DFSDM_CKIN1	USART2_CK
	PD8	-	-	-	-	-	-	-	USART3_TX
	PD9	-	-	-	-	-	-	-	USART3_RX
	PD10	-	-	-	-	-	-	-	USART3_CK
	PD11	-	-	-	-	-	-	-	USART3_CTS
	PD12	-	-	TIM4_CH1	-	-	-	-	USART3_RTS_ DE
	PD13	-	-	TIM4_CH2	-	-	-	-	-
	PD14	-	-	TIM4_CH3	-	-	-	-	-
	PD15	-	-	TIM4_CH4	-	-	-	-	-

6.1.6 Power supply scheme

Figure 13. Power supply scheme



Caution: Each power supply pair (V_{DD}/V_{SS} , V_{DDA}/V_{SSA} etc.) must be decoupled with filtering ceramic capacitors as shown above. These capacitors must be placed as close as possible to, or below, the appropriate pins on the underside of the PCB to ensure the good functionality of the device.



Table 28. Current consumption in Run and Low-power run modes, code with data processing running from SRAM1

Symbol	Parameter	Conditions			TYP					MAX ⁽¹⁾					Unit
		-	Voltage scaling	f _{HCLK}	25 °C	55 °C	85 °C	105 °C	125 °C	25 °C	55 °C	85 °C	105 °C	125 °C	
I _{DD} (Run)	Supply current in Run mode	f _{HCLK} = f _{HSE} up to 48MHz included, bypass mode PLL ON above 48 MHz all peripherals disable	Range 2	26 MHz	2.88	2.94	3.05	3.23	3.58	3.18	3.26	3.40	4.02	4.65	mA
				16 MHz	1.83	1.87	1.98	2.15	2.50	2.01	2.16	2.30	2.72	3.34	
				8 MHz	0.97	1.00	1.11	1.27	1.62	1.07	1.16	1.32	1.73	2.36	
				4 MHz	0.54	0.57	0.67	0.84	1.18	0.59	0.69	0.88	1.23	1.96	
				2 MHz	0.33	0.36	0.46	0.62	0.96	0.37	0.45	0.63	0.98	1.70	
				1 MHz	0.22	0.25	0.35	0.51	0.85	0.25	0.33	0.50	0.86	1.57	
				100 kHz	0.12	0.15	0.25	0.41	0.75	0.15	0.21	0.39	0.74	1.45	
			Range 1	80 MHz	10.2	10.3	10.5	10.7	11.1	11.22	11.57	11.86	12.07	13.11	
				72 MHz	9.25	9.31	9.46	9.68	10.1	10.18	10.41	10.55	10.76	11.80	
				64 MHz	8.25	8.31	8.46	8.67	9.08	9.08	9.37	9.66	9.87	10.91	
				48 MHz	6.26	6.33	6.48	6.69	7.11	6.89	7.11	7.25	7.67	8.50	
				32 MHz	4.22	4.28	4.42	4.63	5.03	4.64	4.86	5.15	5.56	6.19	
				24 MHz	3.20	3.25	3.38	3.59	3.99	3.52	3.70	3.84	4.26	5.09	
				16 MHz	2.18	2.22	2.35	2.55	2.94	2.40	2.55	2.84	3.25	4.09	
I _{DD} (LPRun)	Supply current in low-power run mode	f _{HCLK} = f _{MSI} all peripherals disable FLASH in power-down		2 MHz	242	275	384	562	924	300	380	573	927	1677	μA
				1 MHz	130	162	269	445	809	180	243	435	810	1560	
				400 kHz	61	90	197	374	734	95	160	353	728	1478	
				100 kHz	26	56	163	339	702	55	122	314	679	1429	

1. Guaranteed by characterization results, unless otherwise specified.

Table 30. Typical current consumption in Run and Low-power run modes, with different codes running from Flash, ART disable

Symbol	Parameter	Conditions			TYP	Unit	TYP	Unit
		-	Voltage scaling	Code	25 °C		25 °C	
$I_{DD}(\text{Run})$	Supply current in Run mode	$f_{HCLK} = f_{HSE}$ up to 48 MHz included, bypass mode PLL ON above 48 MHz all peripherals disable	Range 2 $f_{HCLK} = 26 \text{ MHz}$	Reduced code ⁽¹⁾	3.1	mA	119	$\mu\text{A}/\text{MHz}$
				Coremark	2.9		111	
				Dhrystone 2.1	2.8		111	
				Fibonacci	2.7		104	
				While(1)	2.6		100	
			Range 1 $f_{HCLK} = 80 \text{ MHz}$	Reduced code ⁽¹⁾	10.0	mA	125	$\mu\text{A}/\text{MHz}$
				Coremark	9.4		117	
				Dhrystone 2.1	9.1		114	
				Fibonacci	9.0		112	
				While(1)	9.3		116	
$I_{DD}(\text{LPRun})$	Supply current in Low-power run	$f_{HCLK} = f_{MSI} = 2 \text{ MHz}$ all peripherals disable		Reduced code ⁽¹⁾	358	μA	179	$\mu\text{A}/\text{MHz}$
				Coremark	392		196	
				Dhrystone 2.1	390		195	
				Fibonacci	385		192	
				While(1)	385		192	

1. Reduced code used for characterization results provided in [Table 26](#), [Table 27](#), [Table 28](#).

Table 31. Typical current consumption in Run and Low-power run modes, with different codes running from SRAM1

Symbol	Parameter	Conditions			TYP	Unit	TYP	Unit
		-	Voltage scaling	Code	25 °C		25 °C	
$I_{DD}(\text{Run})$	Supply current in Run mode	$f_{HCLK} = f_{HSE}$ up to 48 MHz included, bypass mode PLL ON above 48 MHz all peripherals disable	Range 2 $f_{HCLK} = 26 \text{ MHz}$	Reduced code ⁽¹⁾	2.9	mA	111	$\mu\text{A}/\text{MHz}$
				Coremark	2.9		111	
				Dhrystone 2.1	2.9		111	
				Fibonacci	2.6		100	
				While(1)	2.6		100	
			Range 1 $f_{HCLK} = 80 \text{ MHz}$	Reduced code ⁽¹⁾	10.2	mA	127	$\mu\text{A}/\text{MHz}$
				Coremark	10.4		130	
				Dhrystone 2.1	10.3		129	
				Fibonacci	9.6		120	
				While(1)	9.3		116	
$I_{DD}(\text{LPRun})$	Supply current in Low-power run	$f_{HCLK} = f_{MSI} = 2 \text{ MHz}$ all peripherals disable		Reduced code ⁽¹⁾	242	μA	121	$\mu\text{A}/\text{MHz}$
				Coremark	242		121	
				Dhrystone 2.1	242		121	
				Fibonacci	225		112	
				While(1)	242		121	

1. Reduced code used for characterization results provided in [Table 26](#), [Table 27](#), [Table 28](#).

Table 40. Peripheral current consumption (continued)

Peripheral		Range 1	Range 2	Low-power run and sleep	Unit
AHB	SRAM2	1.6	1.4	1.6	μA/MHz
	TSC	1.8	1.4	1.6	
	All AHB Peripherals	118.5	77.3	87.6	
APB1	AHB to APB1 bridge ⁽³⁾	0.9	0.7	0.9	μA/MHz
	CAN1	4.6	4.0	4.4	
	DAC1	2.4	1.9	2.2	
	I2C1 independent clock domain	3.7	3.1	3.2	
	I2C1 APB clock domain	1.3	1.1	1.5	
	I2C2 independent clock domain	3.7	3.0	3.2	
	I2C2 APB clock domain	1.4	1.1	1.5	
	I2C3 independent clock domain	2.9	2.3	2.5	
	I2C3 APB clock domain	0.9	0.9	1.1	
	LCD	1.0	0.8	0.9	
	LPUART1 independent clock domain	2.1	1.6	2.0	
	LPUART1 APB clock domain	0.6	0.6	0.6	
	LPTIM1 independent clock domain	3.3	2.6	2.9	
	LPTIM1 APB clock domain	0.9	0.8	1.0	
	LPTIM2 independent clock domain	3.1	2.7	2.9	
	LPTIM2 APB clock domain	0.8	0.6	0.7	
	OPAMP	0.4	0.4	0.3	
	PWR	0.5	0.5	0.4	
	SPI2	1.8	1.6	1.6	
	SPI3	2.1	1.7	1.8	
	SWPMI1 independent clock domain	2.3	1.8	2.2	
	SWPMI1 APB clock domain	1.1	1.1	1.0	
	TIM2	6.8	5.7	6.3	
	TIM3	5.4	4.6	5.0	
	TIM4	5.2	4.4	4.9	
	TIM5	6.5	5.5	6.1	
	TIM6	1.1	1.0	1.0	
	TIM7	1.1	0.9	1.0	

Table 40. Peripheral current consumption (continued)

Peripheral		Range 1	Range 2	Low-power run and sleep	Unit
APB1	USART2 independent clock domain	4.1	3.6	3.8	µA/MHz
	USART2 APB clock domain	1.4	1.1	1.5	
	USART3 independent clock domain	4.7	4.1	4.2	
	USART3 APB clock domain	1.5	1.3	1.7	
	UART4 independent clock domain	3.9	3.2	3.5	
	UART4 APB clock domain	1.5	1.3	1.6	
	UART5 independent clock domain	3.9	3.2	3.5	
	UART5 APB clock domain	1.3	1.2	1.4	
	WWDG	0.5	0.5	0.5	
	All APB1 on	84.2	70.7	80.2	
APB2	AHB to APB2 bridge ⁽⁴⁾	1.0	0.9	0.9	
	DFSDM	5.6	4.6	5.3	
	FW	0.7	0.5	0.7	
	SAI1 independent clock domain	2.6	2.1	2.3	
	SAI1 APB clock domain	2.1	1.8	2.0	
	SAI2 independent clock domain	3.3	2.7	3.0	
	SAI2 APB clock domain	2.4	2.1	2.2	
	SDMMC1 independent clock domain	4.7	3.9	4.2	
	SDMMC1 APB clock domain	2.5	1.9	2.1	
	SPI1	2.0	1.6	1.9	
	SYSCFG/VREFBUF/COMP	0.6	0.4	0.5	
	TIM1	8.3	6.9	7.9	
	TIM8	8.6	7.1	8.1	
	TIM15	4.1	3.4	3.9	
	TIM16	3.0	2.5	2.9	
	TIM17	3.0	2.4	2.9	
	USART1 independent clock domain	4.9	4.0	4.4	
	USART1 APB clock domain	1.5	1.3	1.7	
	All APB2 on	56.8	43.3	48.2	
ALL		256.8	189.6	215.5	

High-speed external clock generated from a crystal/ceramic resonator

The high-speed external (HSE) clock can be supplied with a 4 to 48 MHz crystal/ceramic resonator oscillator. All the information given in this paragraph are based on design simulation results obtained with typical external components specified in [Table 45](#). In the application, the resonator and the load capacitors have to be placed as close as possible to the oscillator pins in order to minimize output distortion and startup stabilization time. Refer to the crystal resonator manufacturer for more details on the resonator characteristics (frequency, package, accuracy).

Table 45. HSE oscillator characteristics⁽¹⁾

Symbol	Parameter	Conditions ⁽²⁾	Min	Typ	Max	Unit
f_{OSC_IN}	Oscillator frequency	-	4	8	48	MHz
R_F	Feedback resistor	-	-	200	-	k Ω
$I_{DD(HSE)}$	HSE current consumption	During startup ⁽³⁾	-	-	5.5	mA
		$V_{DD} = 3\text{ V}$, $R_m = 30\ \Omega$, $CL = 10\text{ pF}@8\text{ MHz}$	-	0.44	-	
		$V_{DD} = 3\text{ V}$, $R_m = 45\ \Omega$, $CL = 10\text{ pF}@8\text{ MHz}$	-	0.45	-	
		$V_{DD} = 3\text{ V}$, $R_m = 30\ \Omega$, $CL = 5\text{ pF}@48\text{ MHz}$	-	0.68	-	
		$V_{DD} = 3\text{ V}$, $R_m = 30\ \Omega$, $CL = 10\text{ pF}@48\text{ MHz}$	-	0.94	-	
		$V_{DD} = 3\text{ V}$, $R_m = 30\ \Omega$, $CL = 20\text{ pF}@48\text{ MHz}$	-	1.77	-	
G_m	Maximum critical crystal transconductance	Startup	-	-	1.5	mA/V
$t_{SU(HSE)}^{(4)}$	Startup time	V_{DD} is stabilized	-	2	-	ms

1. Guaranteed by design.

2. Resonator characteristics given by the crystal/ceramic resonator manufacturer.

3. This consumption level occurs during the first 2/3 of the $t_{SU(HSE)}$ startup time

4. $t_{SU(HSE)}$ is the startup time measured from the moment it is enabled (by software) to a stabilized 8 MHz oscillation is reached. This value is measured for a standard crystal resonator and it can vary significantly with the crystal manufacturer

For C_{L1} and C_{L2} , it is recommended to use high-quality external ceramic capacitors in the 5 pF to 20 pF range (typ.), designed for high-frequency applications, and selected to match the requirements of the crystal or resonator (see [Figure 18](#)). C_{L1} and C_{L2} are usually the same size. The crystal manufacturer typically specifies a load capacitance which is the series combination of C_{L1} and C_{L2} . PCB and MCU pin capacitance must be included (10 pF can be used as a rough estimate of the combined pin and board capacitance) when sizing C_{L1} and C_{L2} .

Output voltage levels

Unless otherwise specified, the parameters given in the table below are derived from tests performed under the ambient temperature and supply voltage conditions summarized in [Table 22: General operating conditions](#). All I/Os are CMOS- and TTL-compliant (FT OR TT unless otherwise specified).

Table 59. Output voltage characteristics⁽¹⁾

Symbol	Parameter	Conditions	Min	Max	Unit
V_{OL}	Output low level voltage for an I/O pin	CMOS port ⁽²⁾ $ I_{IO} = 8 \text{ mA}$ $V_{DDIOx} \geq 2.7 \text{ V}$	-	0.4	V
V_{OH}	Output high level voltage for an I/O pin		$V_{DDIOx} - 0.4$	-	
$V_{OL}^{(3)}$	Output low level voltage for an I/O pin	TTL port ⁽²⁾ $ I_{IO} = 8 \text{ mA}$ $V_{DDIOx} \geq 2.7 \text{ V}$	-	0.4	
$V_{OH}^{(3)}$	Output high level voltage for an I/O pin		2.4	-	
$V_{OL}^{(3)}$	Output low level voltage for an I/O pin	$ I_{IO} = 20 \text{ mA}$ $V_{DDIOx} \geq 2.7 \text{ V}$	-	1.3	
$V_{OH}^{(3)}$	Output high level voltage for an I/O pin		$V_{DDIOx} - 1.3$	-	
$V_{OL}^{(3)}$	Output low level voltage for an I/O pin	$ I_{IO} = 4 \text{ mA}$ $V_{DDIOx} \geq 1.62 \text{ V}$	-	0.45	
$V_{OH}^{(3)}$	Output high level voltage for an I/O pin		$V_{DDIOx} - 0.45$	-	
$V_{OL}^{(3)}$	Output low level voltage for an I/O pin	$ I_{IO} = 2 \text{ mA}$ $1.62 \text{ V} \geq V_{DDIOx} \geq 1.08 \text{ V}$	-	$0.35 \times V_{DDIOx}$	
$V_{OH}^{(3)}$	Output high level voltage for an I/O pin		$0.65 \times V_{DDIOx}$	-	
$V_{OLFM+}^{(3)}$	Output low level voltage for an FT I/O pin in FM+ mode (FT I/O with "f" option)	$ I_{IO} = 20 \text{ mA}$ $V_{DDIOx} \geq 2.7 \text{ V}$	-	0.4	
		$ I_{IO} = 10 \text{ mA}$ $V_{DDIOx} \geq 1.62 \text{ V}$	-	0.4	
		$ I_{IO} = 2 \text{ mA}$ $1.62 \text{ V} \geq V_{DDIOx} \geq 1.08 \text{ V}$	-	0.4	

1. The I_{IO} current sourced or sunk by the device must always respect the absolute maximum rating specified in [Table 19: Voltage characteristics](#), and the sum of the currents sourced or sunk by all the I/Os (I/O ports and control pins) must always respect the absolute maximum ratings ΣI_{IO} .
2. TTL and CMOS outputs are compatible with JEDEC standards JESD36 and JESD52.
3. Guaranteed by design.

Input/output AC characteristics

The definition and values of input/output AC characteristics are given in [Figure 23](#) and [Table 60](#), respectively.

Unless otherwise specified, the parameters given are derived from tests performed under the ambient temperature and supply voltage conditions summarized in [Table 22: General operating conditions](#).

Table 66. ADC accuracy - limited test conditions 2⁽¹⁾(2)(3) (continued)

Sym- bol	Parameter	Conditions ⁽⁴⁾			Min	Typ	Max	Unit
THD	Total harmonic distortion	ADC clock frequency \leq 80 MHz, Sampling rate \leq 5.33 Msps, $2\text{ V} \leq V_{DDA}$	Single ended	Fast channel (max speed)	-	-74	-65	dB
				Slow channel (max speed)	-	-74	-67	
			Differential	Fast channel (max speed)	-	-79	-70	
				Slow channel (max speed)	-	-79	-71	

1. Guaranteed by design.
2. ADC DC accuracy values are measured after internal calibration.
3. ADC accuracy vs. negative Injection Current: Injecting negative current on any analog input pins should be avoided as this significantly reduces the accuracy of the conversion being performed on another analog input. It is recommended to add a Schottky diode (pin to ground) to analog pins which may potentially inject negative current.
4. The I/O analog switch voltage booster is enable when $V_{DDA} < 2.4\text{ V}$ (BOOSTEN = 1 in the SYSCFG_CFGR1 when $V_{DDA} < 2.4\text{ V}$). It is disable when $V_{DDA} \geq 2.4\text{ V}$. No oversampling.

6.3.27 Communication interfaces characteristics

I²C interface characteristics

The I2C interface meets the timings requirements of the I²C-bus specification and user manual rev. 03 for:

- Standard-mode (Sm): with a bit rate up to 100 kbit/s
- Fast-mode (Fm): with a bit rate up to 400 kbit/s
- Fast-mode Plus (Fm+): with a bit rate up to 1 Mbit/s.

The I2C timings requirements are guaranteed by design when the I2C peripheral is properly configured (refer to RM0351 reference manual).

The SDA and SCL I/O requirements are met with the following restrictions: the SDA and SCL I/O pins are not “true” open-drain. When configured as open-drain, the PMOS connected between the I/O pin and V_{DDIOx} is disabled, but is still present. Only FT_f I/O pins support Fm+ low level output current maximum requirement. Refer to [Section 6.3.14: I/O port characteristics](#) for the I2C I/Os characteristics.

All I2C SDA and SCL I/Os embed an analog filter. Refer to the table below for the analog filter characteristics:

Table 82. I2C analog filter characteristics⁽¹⁾

Symbol	Parameter	Min	Max	Unit
t _{AF}	Maximum pulse width of spikes that are suppressed by the analog filter	50 ⁽²⁾	260 ⁽³⁾	ns

1. Guaranteed by design.
2. Spikes with widths below t_{AF(min)} are filtered.
3. Spikes with widths above t_{AF(max)} are not filtered

Table 85. QUADSPI characteristics in DDR mode⁽¹⁾

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
F_{CK} $1/t_{(CK)}$	Quad SPI clock frequency	$1.71 < V_{DD} < 3.6$ V, $C_{LOAD} = 20$ pF Voltage Range 1	-	-	40	MHz
		$2 < V_{DD} < 3.6$ V, $C_{LOAD} = 20$ pF Voltage Range 1	-	-	48	
		$1.71 < V_{DD} < 3.6$ V, $C_{LOAD} = 15$ pF Voltage Range 1	-	-	48	
		$1.71 < V_{DD} < 3.6$ V $C_{LOAD} = 20$ pF Voltage Range 2	-	-	26	
$t_{w(CKH)}$	Quad SPI clock high and low time	$f_{AHBCLK} = 48$ MHz, presc=0	$t_{(CK)}/2-2$	-	$t_{(CK)}/2$	ns
$t_{w(CKL)}$			$t_{(CK)}/2$	-	$t_{(CK)}/2+2$	
$t_{sf(IN)}; t_{sr(IN)}$	Data input setup time	Voltage Range 1 and 2	3.5	-	-	
$t_{hf(IN)}; t_{hr(IN)}$	Data input hold time		6.5	-	-	
$t_{vf(OUT)}; t_{vr(OUT)}$	Data output valid time	Voltage Range 1	-	11	12	
		Voltage Range 2		15	19	
$t_{hf(OUT)}; t_{hr(OUT)}$	Data output hold time	Voltage Range 1	6	-	-	
		Voltage Range 2	8	-		

1. Guaranteed by characterization results.

Figure 31. Quad SPI timing diagram - SDR mode

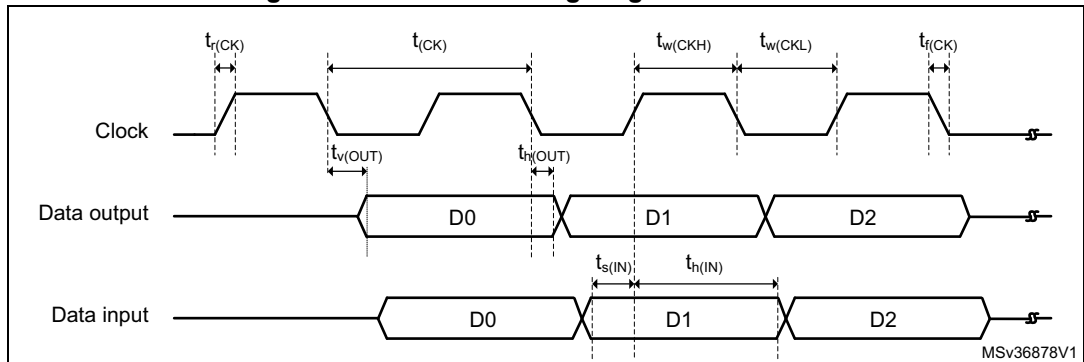


Figure 32. Quad SPI timing diagram - DDR mode

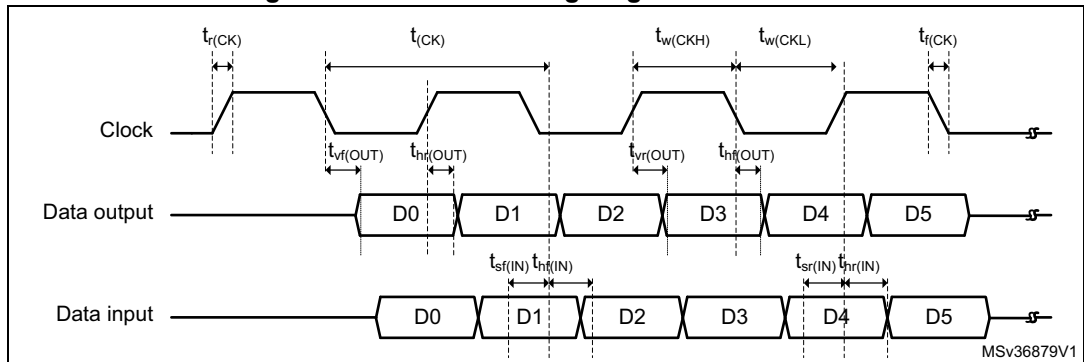


Figure 37. Asynchronous non-multiplexed SRAM/PSRAM/NOR read waveforms

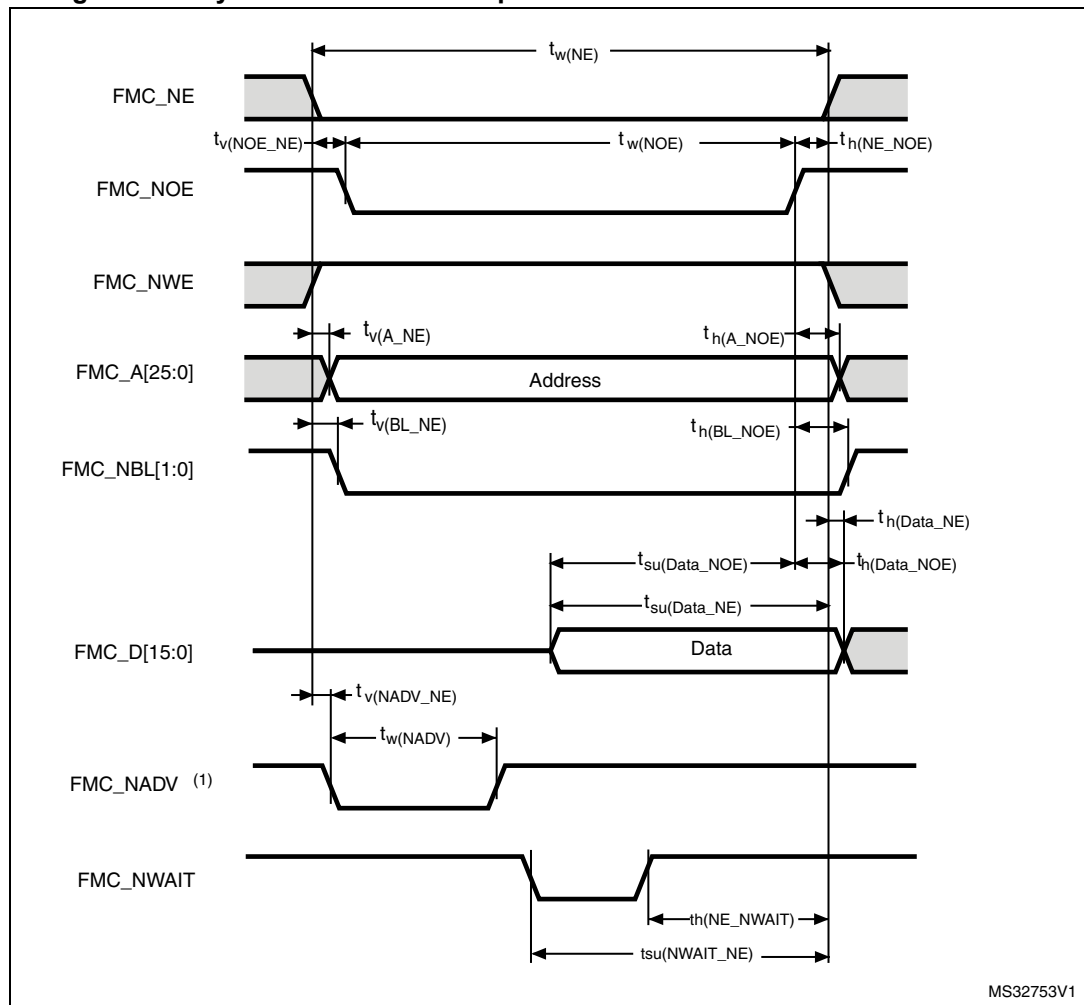
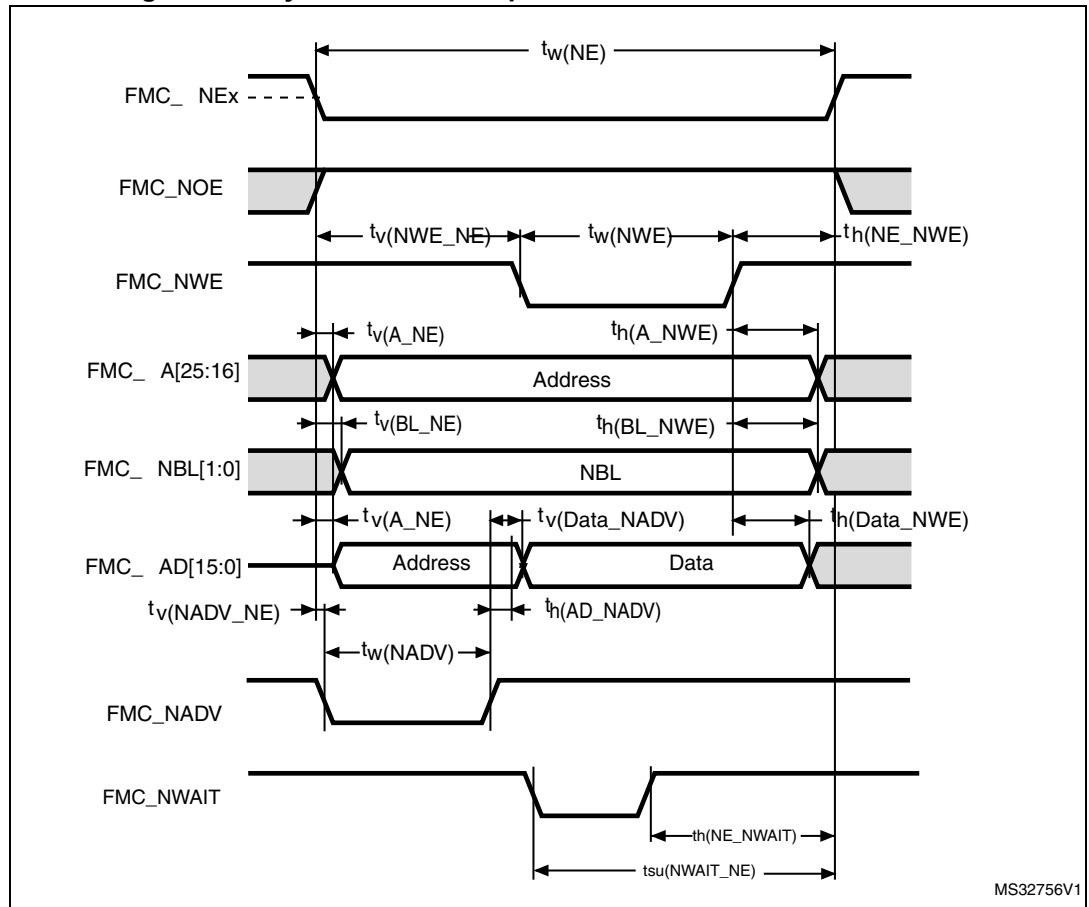


Figure 40. Asynchronous multiplexed PSRAM/NOR write waveforms



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